

GENERAL DESCRIPTION

OB2273A is a highly integrated current mode PWM control IC optimized for high performance, low standby power and cost effective offline flyback converter applications.

PWM switching frequency at normal operation is internally fixed and is trimmed to tight range. At no load or light load condition, the IC operates in extended 'burst mode' to minimize switching loss. Lower standby power and higher conversion efficiency is thus achieved.

VDD low startup current and low operating current contribute to a reliable power on startup and low standby design with OB2273A.

OB2273A offers complete protection coverage with auto-recovery including Cycle-by-Cycle current limiting (OCP), over load protection (OLP), VDD under voltage lockout (UVLO), over temperature protection (OTP), and over voltage (fixed or adjustable) protection (OVP). Excellent EMI performance is achieved with On-Bright proprietary frequency shuffling technique.

The tone energy at below 20KHZ is minimized in the design and audio noise is eliminated during operation.

OB2273A is offered in SOT23-6 package.

FEATURES

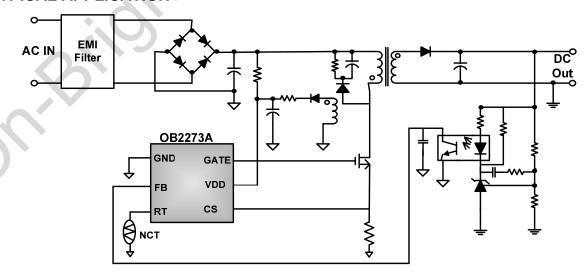
- Level 5 compliance with <100mW standby power at universal AC input.
- Power on Soft Start Reducing MOSFET Vds Stress
- Frequency shuffling for EMI
- Extended Burst Mode Control For Improved Efficiency and Minimum Standby Power Design
- Audio Noise Free Operation
- Fixed 65KHZ Switching Frequency
- Comprehensive Protection Coverage
 - VDD Under Voltage Lockout with Hysteresis (UVLO)
 - Cycle-by-cycle over current threshold setting for constant output power limiting over universal input voltage range
 - Overload Protection (OLP) with autorecovery
 - Over Temperature Protection (OTP) with auto-recovery
 - VDD Over voltage Protection(OVP) with auto-recovery
 - Adjustable OVP through external Zener

APPLICATIONS

Offline AC/DC flyback converter for

- Battery Charger
- Power Adaptor
- Set-Top Box Power Supplies
- Open-frame SMPS

TYPICAL APPLICATION

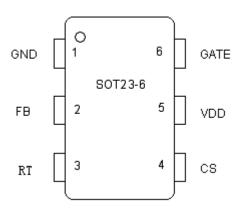




GENERAL INFORMATION

Pin Configuration

The OB2273A is offered in SOT23-6 package, shown as below.



Ordering Information

<u> </u>	
Part Number	Description
OB2273AMP	SOT23-6, Pb-free in T&R

Package Dissipation Rating

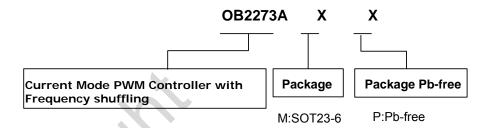
Package	RθJA(℃/W)
SOT23-6	200

Absolute Maximum Ratings

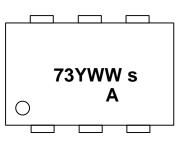
Absolute Maximum Ratings						
Parameter	Value					
VDD DC Supply Voltage	VOVP-1V					
VDD Zener Clamp Voltage ^{Note}	VDD_Clamp+0.1V					
VDD DC Clamp Current	10 mA					
FB Input Voltage	-0.3 to 7V					
Sense Input Voltage	-0.3 to 7V					
RT Input Voltage	-0.3 to 7V					
Min/Max Operating Junction Temperature TJ	-40 to 150 ℃					
Min/Max Storage Temperature Tstg	-55 to 150 ℃					
Lead Temperature (Soldering, 10secs)	260 ℃					

Note: VDD_Clamp has a typical value of 32V

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute maximum-rated conditions for extended periods may affect device reliability.



Marking Information



Y:Year Code WW:Week Code(01-52)

S:Internal Code(Optional)

A:Character Code



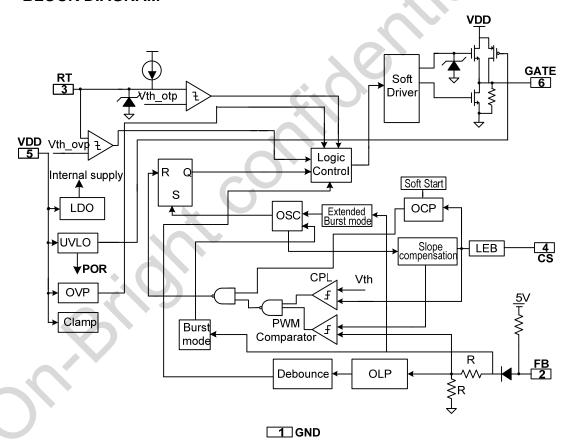
TERMINAL ASSIGNMENTS

Pin Name	I/O	Description
GND	Р	Ground
FB	I	Feedback input pin. The PWM duty cycle is determined by voltage level into this pin and the current-sense signal at Pin 4.
RT	I	Dual function pin. Either connected through a NTC resistor to ground for over temperature shutdown/latch control or connected through Zener to VDD for adjustable over voltage protection
CS		Current sense input
VDD	Р	Power Supply
Gate	Totem-pole gate driver output for power Mosfet	

RECOMMENDED OPERATING CONDITION

Symbol	Parameter	Min/Max	Unit
VDD	VDD Supply Voltage	12 to 25	V
T _A	Operating Ambient Temperature	-20 to 85	$^{\circ}$

BLOCK DIAGRAM





ELECTRICAL CHARACTERISTICS

(T_A = 25°C, VDD=18V, unless otherwise noted)

Symbol	(T _A = 25 ℃, VDD=18V, unless otherwise noted) Symbol Parameter Test Conditions Min Typ Max Unit						
-			IVIIII	Тур	IVIAX	Unit	
Supply Voltage (VDD)							
Istartup VDD Start up Current		VDD=UVLO(OFF)- 1V, measure leakage current into VDD		5	20	uA	
I_VDD_Operation	Operation Current	V _{FB} =3V		1.8	2.5	mA	
UVLO(ON)	VDD Under Voltage Lockout Enter		8	9	10	٧	
UVLO(OFF)	VDD Under Voltage Lockout Exit (Recovery)		14.3	15.3	16.3	V	
Vpull-up	Pull-up PMOS active			13		V	
Vdd_clamp		Ivdd=10mA	30	32	34	V	
OVP(ON)	Over voltage protection voltage	CS=0V,FB=3V Ramp up VDD until gate clock is off	26	28	30	V	
Feedback Input S	ection(FB Pin)				I.	I.	
V _{FB} Open	V _{FB} Open Loop Voltage	XI	3.9	4.2		V	
Avcs	PWM input gain △VFB/△VCS			2		V/V	
Maximum duty cycle	Max duty cycle @ VDD=14V,VFB=3V,VCS=0V		75	80	85	%	
Vref_green	The threshold enter green mode	XO		2		٧	
Vref burst H	The threshold exit burst mode			1.275		V	
Vref_burst_L	The threshold enter burst mode			1.175		V	
I _{FB} _Short FB pin short circuit current		Short FB pin to GND and measure current		0.4		mA	
V _{TH} _PL	V _{TH} _PL Power Limiting FB Threshold Voltage			3.7		V	
T _D _PL			80	88	96	mSec	
Z _{FB} _IN Input Impedance				16		Kohm	
Current Sense Inp	urrent Sense Input(CS Pin)						
SST	Soft start time			4		ms	
T_blanking	Leading edge blanking time			220		ns	
Z _{SENSE} _IN	Input Impedance			40		Kohm	
T _D OC Over Current Detection and Control Delay		From Over Current Occurs till the Gatedrive output start to turn off		120		nSec	
V _{TH} _OC	Internal Current Limiting Threshold Voltage with zero duty cycle		0.725	0.75	0.775	V	
Vocp_clamping				0.9		V	
Oscillator	Oscillator VDD=14V FF						
Fosc			60	65	70	KHZ	
△f_OSC	Frequency jittering			+/-4		%	
F_shuffling	Shuffling frequency			32		Hz	
△f_Temp	Frequency Temperature			1		%	

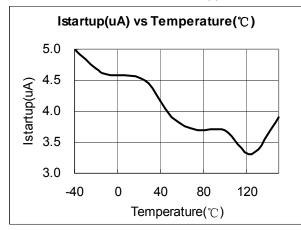


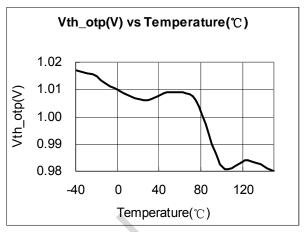
	1						
$\triangle f_VDD$	Frequency Voltage Stability			1		%	
F_Burst	Burst Mode Switch Frequency			22		KHZ	
Gate driver	Gate driver						
VOL	Ouput low level @ VDD=14V, lo=5mA				1	V	
VOH Ouput high level @ VDD=14V, lo=20mA			6			V	
V_clamping	Output clamp voltage			12		V	
T_r	Output rising time 1V ~ 12V @ CL=1000pF			175		nS	
T_f Output falling time 12V ~ 1V @ CL=1000pF				85		nS	
Over temperature	Over temperature protection						
IRT	Output current of RT pin		95	100	105	uA	
VOTP	Threshold voltage for OTP		0.95	1	1.05	V	
Td_OTP	OTP debounce time			6		Cycle	
VRT_FL	Float voltage at RT pin			2.3		V	
Vth_OVP External OVP threshold voltage				4		V	

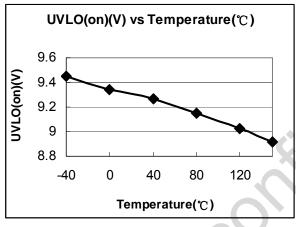


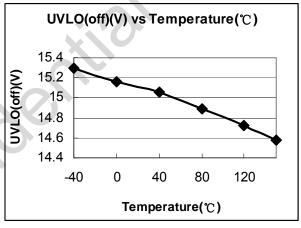
CHARACTERIZATION PLOTS

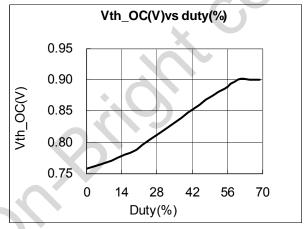
VDD = 18V, TA = 25^oC condition applies if not otherwise noted.

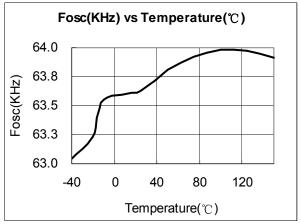














OPERATION DESCRIPTION

OB2273A is a highly integrated current mode PWM control IC optimized for high performance, low standby power and cost effective offline flyback converter applications. The 'Extended burst mode' control greatly reduces the standby power consumption and helps the design easily to meet the international power conservation requirements.

Startup Current and Start up Control

Startup current of OB2273A is designed to be very low so that VDD could be charged up above UVLO threshold level and device starts up quickly. A large value startup resistor can therefore be used to minimize the power loss yet achieve a reliable startup in application.

Operating Current

The Operating current of OB2273A is low at 1.8mA. Good efficiency is achieved with OB2273A low operating current together with the 'Extended burst mode' control features.

Soft Start

OB2273A features an internal 4ms soft start to soften the electrical stress occurring in the power supply during startup. It is activated during the power on sequence. As soon as VDD reaches UVLO(OFF), the CS peak voltage is gradually increased to the maximum level. Every restart up is followed by a soft start.

Frequency shuffling for EMI improvement

The frequency Shuffling (switching frequency modulation) is implemented in OB2273A. The oscillation frequency is modulated so that the tone energy is spread out. The spread spectrum minimizes the conduction band EMI and therefore eases the system design.

Extended Burst Mode Operation

At light load or zero load condition, most of the power dissipation in a switching mode power supply is from switching loss on the MOSFET, the core loss of the transformer and the loss on the snubber circuit. The magnitude of power loss is in proportion to the switching frequency. Lower switching frequency leads to the reduction on the power loss and thus conserves the energy.

The switching frequency is internally adjusted at no load or light load condition. The switch frequency reduces at light/no load condition to improve the conversion efficiency. At light load or

no load condition, the FB input drops below burst mode threshold level and device enters Burst Mode control. The Gate drive output switches when VDD voltage drops below a preset level and FB input is active to output an on state. Otherwise the gate drive remains at off state to minimize the switching loss and reduces the standby power consumption to the greatest extend.

The switching frequency control also eliminates the audio noise at any loading conditions.

Oscillator Operation

The switching frequency is internally fixed at 65KHZ. No external frequency setting components are required for PCB design simplification.

• Current Sensing and Leading Edge Blanking
Cycle-by-Cycle current limiting is offered in
OB2273A current mode PWM control. The switch
current is detected by a sense resistor into the cs
pin. An internal leading edge blanking circuit
chops off the sensed voltage spike at initial
internal power MOSFET on state due to snubber
diode reverse recovery and surge gate current of
power MOSFET. The current limiting comparator
is disabled and cannot turn off the internal power
MOSFET during the blanking period. The PWM
duty cycle is determined by the current sense
input voltage and the FB input voltage.

• Internal Synchronized Slope Compensation

Built-in slope compensation circuit adds voltage ramp onto the current sense input voltage for PWM generation. This greatly improves the close loop stability at CCM and prevents the subharmonic oscillation and thus reduces the output ripple voltage.

Drive

The power MOSFET is driven by a dedicated gate driver for power switch control. Too weak the gate drive strength results in higher conduction and switch loss of MOSFET while too strong gate drive results the compromise of EMI.

A good tradeoff is achieved through the built-in totem pole gate design with right output strength and dead time control. The low idle loss and good EMI system design is easier to achieve with this dedicated control scheme.



• Protection Controls

Good power supply system reliability is achieved with auto-recovery protection features including Cycle-by-Cycle current limiting (OCP), Over Load Protection (OLP), Under Voltage Lockout on VDD (UVLO), over temperature protection (OTP) and fixed or adjustable VDD over voltage protection (OVP).

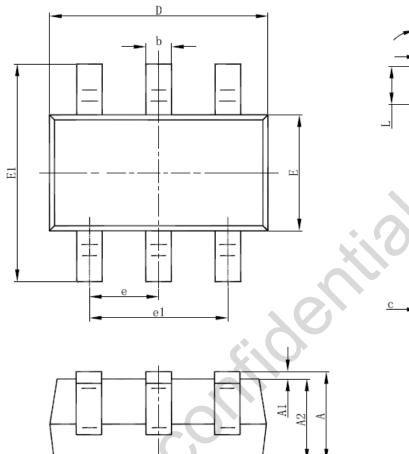
With On-Bright Proprietary technology, the OCP is line voltage compensated to achieve constant output power limit over the universal input voltage range.

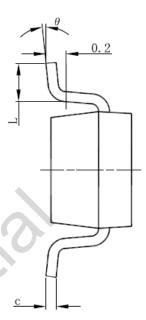
At overload condition when FB input voltage exceeds power limit threshold value for more than TD_PL, control circuit reacts to shut down the converter. It restarts when VDD voltage drops below UVLO limit.



PACKAGE MECHANICAL DATA

SOT-23-6L PACKAGE OUTLINE DIMENSIONS





Symbol	Dimensions I	n Millimeters	Dimension	s In Inches
Symbol	Min	Max	Min	Max
Α	1.000	1.450	0.039	0.057
A1	0.000	0.150	0.000	0.006
A2	0.900	1.300	0.035	0.051
b	0.300	0.500	0.012	0.020
С	0.080	0.220	0.003	0.009
D	2.800	3.020	0.110	0.119
E	1.500	1.726	0.059	0.068
E1	2.600	3.000	0.102	0.118
е	0.950 (BSC)		0.037	(BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°



IMPORTANT NOTICE

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